

SFH620A-1, SFH620A-2, SFH620A-3
SFH620A-1X, SFH620A-2X, SFH620A-3X



ISO COM
COMPONENTS

AC INPUT PHOTOTRANSISTOR OPTICALLY COUPLED ISOLATORS



APPROVALS

- UL recognised, File No. E91231
Package Code "EE"
- 'X' SPECIFICATION APPROVALS
- VDE 0884 in 3 available lead form : -
- STD
- G form
- SMD approved to CECC 00802

DESCRIPTION

The SFH620A series of optically coupled isolators consist of inverse parallel infrared light emitting diodes and NPN silicon photo transistors in space efficient dual in line plastic packages.

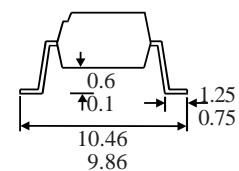
FEATURES

- Options :-
10mm lead spread - add G after part no.
Surface mount - add SM after part no.
Tape&reel - add SMT&R after part no.
- Low input current $\pm 1\text{mA}$ I_F
- High Current Transfer Ratios
(40-320% at $\pm 10\text{mA}$, 13% min at $\pm 1\text{mA}$)
- High Isolation Voltage (5.3kV_{RMS}, 7.5kV_{PK})
- High BV_{CEO} (70V min)
- AC or polarity insensitive input
- All electrical parameters 100% tested
- Custom electrical selections available

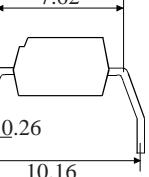
APPLICATIONS

- Computer terminals
- Industrial systems controllers
- Measuring instruments
- Telephone sets, Telephone exchanges
- Signal transmission between systems of different potentials and impedances

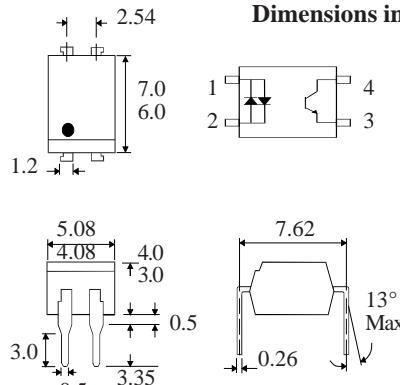
OPTION SM SURFACE MOUNT



OPTION G



Dimensions in mm



ABSOLUTE MAXIMUM RATINGS (25°C unless otherwise specified)

Storage Temperature	—	-55°C to + 125°C
Operating Temperature	—	-30°C to + 100°C
Lead Soldering Temperature	(1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	—	$\pm 50\text{mA}$
Power Dissipation	—	70mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV _{CEO}	—	70V
Emitter-collector Voltage BV _{ECO}	—	6V
Collector Current	—	50mA
Power Dissipation	—	150mW

POWER DISSIPATION

Total Power Dissipation	—	200mW
(derate linearly 2.67mW/°C above 25°C)		

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ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)			1.65	V	$I_F = \pm 50\text{mA}$
Output	Collector-emitter Breakdown (BV_{CEO}) (Note 2)	70			V	$I_C = 1\text{mA}$
	Emitter-collector Breakdown (BV_{ECO})	6			V	$I_E = 100\mu\text{A}$
	Collector-emitter Dark Current (I_{CEO}) SFH620A-1,2 SFH620A-3			50 100	nA nA	$V_{CE} = 10\text{V}$
Coupled	Current Transfer Ratio (CTR) (Note 2) SFH620A-1 SFH620A-2 SFH620A-3	40 63 100		125 200 320	%	$\pm 10\text{mA } I_F, 5\text{V } V_{CE}$
	SFH620A-1 SFH620A-2 SFH620A-3	13 22 34			%	$\pm 1\text{mA } I_F, 5\text{V } V_{CE}$
	Collector-emitter Saturation Voltage V_{CESAT}			0.4	V	$\pm 10\text{mA } I_F, 2.5\text{mA } I_C$
	Input to Output Isolation Voltage V_{ISO}	5300 7500			V_{RMS} V_{PK}	See note 1 See note 1
	Input-output Isolation Resistance R_{ISO}	5×10^{10}			Ω	$V_{IO} = 500\text{V}$ (note 1)
	Response Time (Rise), t_r			4	μs	$V_{CE} = 2\text{V}, I_C = 2\text{mA}$
	Response Time (Fall), t_f			3	μs	$R_L = 100\Omega$

Note 1 Measured with input leads shorted together and output leads shorted together.

Note 2 Special Selections are available on request. Please consult the factory.

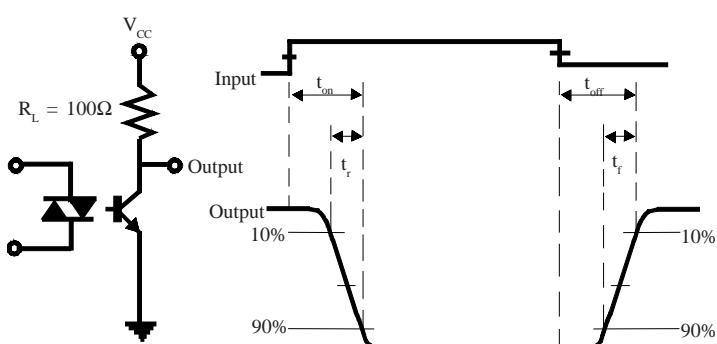
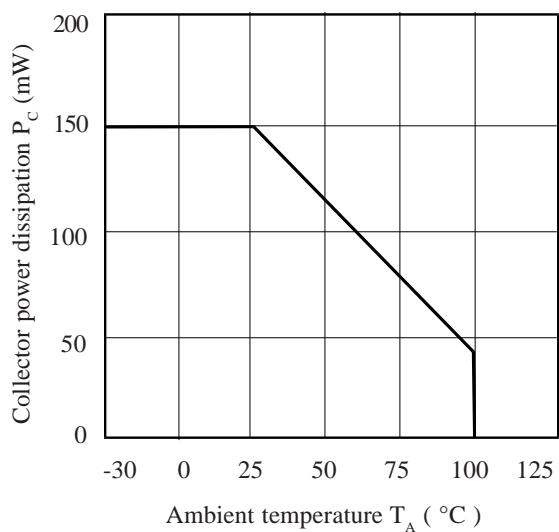
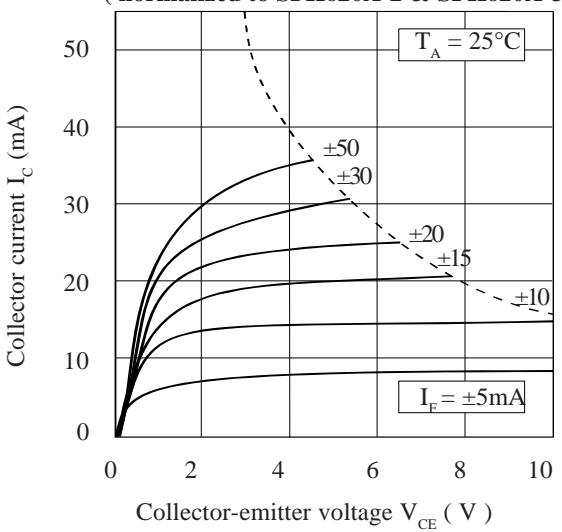
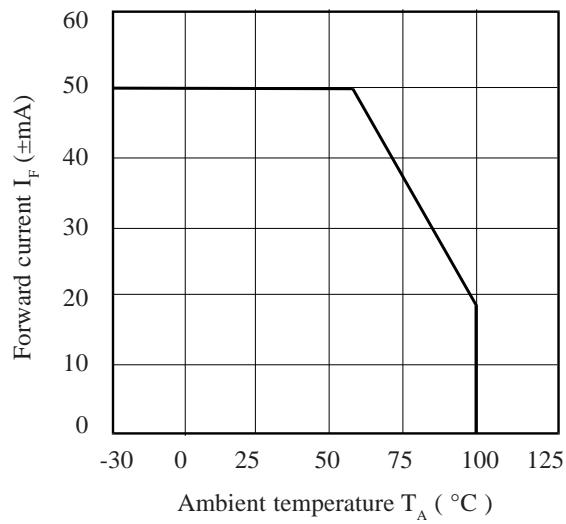
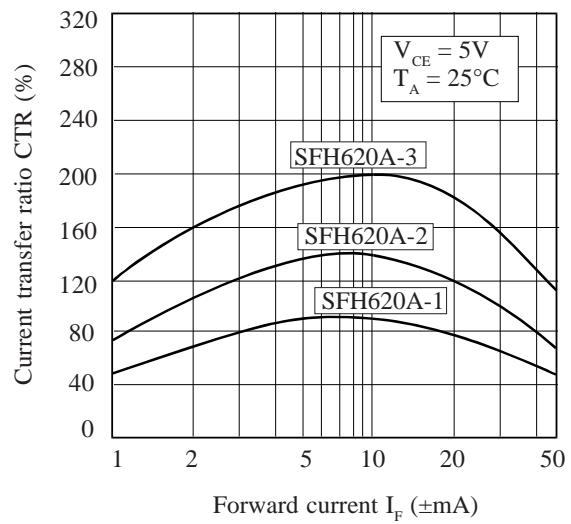
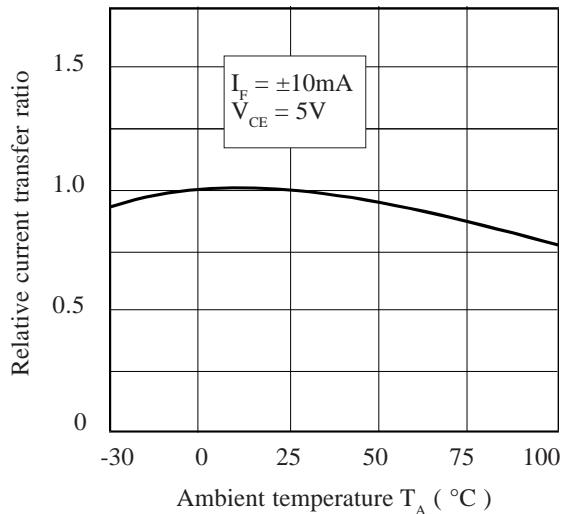


FIG 1

Collector Power Dissipation vs. Ambient Temperature**Collector Current vs. Collector-emitter Voltage
(normalized to SFH620A-2 & SFH620A-3)****Forward Current vs. Ambient Temperature****Current Transfer Ratio vs. Forward Current****Relative Current Transfer Ratio
vs. Ambient Temperature****Collector-emitter Saturation
Voltage vs. Ambient Temperature**